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August 2015



### FUSB340 USB 3.1 SuperSpeed 10 Gbps Switch

#### Features

- 10 GHz Typical Bandwidth
- USB 3.1 SuperSpeed 5 Gbps and 10 Gbps Switch
- -1.0 dB Typical Insertion Loss at 2.5 GHz
- Low Active Power of 12 µA Typical
- Low Shutdown Power of < 1 µA Max.</p>
- 2 kV HBM ESD Protection
- Small Packaging, 18 Lead TMLP
- Wide V<sub>DD</sub> Operating Range, 1.5 V-5.0 V

#### Applications

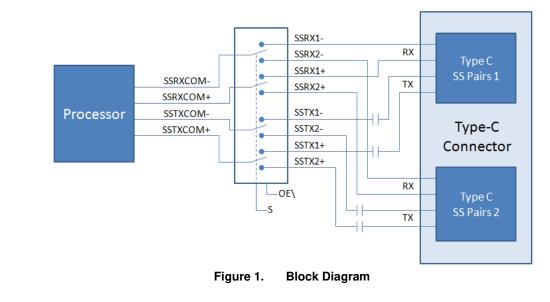
- Smartphones
- Tablets
- Notebooks

#### Description

The FUSB340 is a 2:1 data switch for USB SuperSpeed Gen1 and Gen2, 5 Gbps and 10 Gbps data. It is targeted at the mobile device market and for use in Type-C applications where a reversible cable requires a switch.

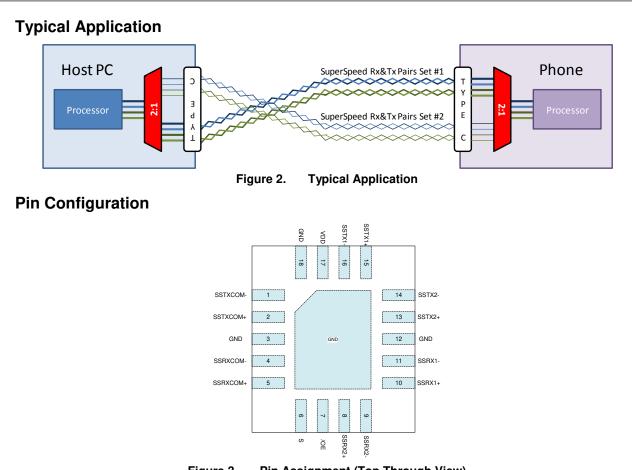
The FUSB340 data switch offers superior performance various high speed data transmission protocols:

- USB 3.1 SuperSpeed (Gen 2), 10 Gbps
- PCI Express, Gen 3
- SATA
- Fibre Channel
- Display Port 1.3



#### **Ordering Information**

Part Number	Operating Temperature Range	Package	Packing Method	
FUSB340TMX	-40 to 85°C	18-Lead, Quad, Ultra-ultrathin Molded Leadless Package (TMLP), 2.0 mm x 2.8 mm x 0.375 mm	Tape and Reel	





#### **Pin Descriptions**

Pin #	Name	Туре	Description		
1	SSTXCOM-	SW	SuperSpeed TX- Common		
2	SSTXCOM+	SW	SuperSpeed TX+ Common		
3	GND	GND	Ground (connected to die attach pad)		
4	SSRXCOM-	SW	SuperSpeed RX- Common		
5	SSRXCOM+	SW	SuperSpeed RX+ Common		
6	S	Input	Switch Select (0=SW1, 1=SW2)		
7	/OE	Input	Output Enable (0=Switches Enabled, 1=Switches Disabled)		
8	SSRX2+	SW	SuperSpeed RX2+		
9	SSRX2-	SW	SuperSpeed RX2-		
10	SSRX1+	SW	SuperSpeed RX1+		
11	SSRX1-	SW	SuperSpeed RX1-		
12	GND	GND	Ground (connected to die attach pad)		
13	SSTX2+	SW	SuperSpeed TX2+		
14	SSTX2-	SW	SuperSpeed TX2-		
15	SSTX1+	SW	SuperSpeed TX1+		
16	SSTX1-	SW	SuperSpeed TX1-		
17	V <sub>DD</sub>	VDD	Device Power		
18	GND	GND	Ground		

#### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
V <sub>DD</sub>	Supply Voltage	-0.5	6.0	V	
V <sub>CNTRL</sub>	DC Input Voltage (S, /OE) <sup>(1)</sup>	-0.5	V <sub>DD</sub>	V	
V <sub>SW</sub>	DC Switch I/O Voltage <sup>(1,2)</sup>	-0.3	2.1	V	
I <sub>IK</sub>	DC Input Diode Current	-50		mA	
I <sub>sw</sub>	DC Switch Current		25	mA	
T <sub>STG</sub>	Storage Temperature	-65	+150	°C	
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)		1		
	Human Body Model, JEDEC: JESD22-A114	All Pins	2		
ESD	IEC 61000-2-4, Level 4, for Switch Pins	Contact	8		kV
230	Air		15		ΓV
	Charged Device Model, JESD22-C101	1			

Notes:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

2. V<sub>SW</sub> refers to analog data switch paths.

#### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V <sub>DD</sub>	Supply Voltage	1.5	5.0	V
tramp(VDD)	Power Supply Slew Rate	100	1000	μs/V
V <sub>CNTRL</sub>	Control Input Voltage (S, /OE) <sup>(3)</sup>	0	5.0	V
V <sub>SW</sub>	Switch I/O Voltage (Both SSUSB Switch Paths)	0	2.0	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

Note:

3. The control inputs must be held HIGH or LOW; they must not float.

### **DC and Transient Characteristics**

All typical values are at TA=25°C unless otherwise specified.

Symbol	Parameter	Condition	V <sub>DD</sub> (V)	T <sub>A</sub> = -40⁰C to +85⁰C			11
				Min.	Тур.	Max.	Unit
VIK	Clamp Diode Voltage S, /OE	I <sub>IN</sub> =-18 mA	1.5	-1.2		-0.6	V
I <sub>IK</sub>	Clamp Diode Current (Switch Pins)	V <sub>IN</sub> =-0.3 V	0			18	μA
		S, /OE	1.5	1.30			V
VIH	Control Input Voltage High	S, /OE	3.6	1.4			V
		S, /OE	5.0	1.5			V
		S, /OE	1.5			0.4	V
VIL	Control Input Voltage Low	S, /OE	3.6			0.4	V
		S, /OE	5.0			0.4	V
I <sub>IN</sub>	Control Input Leakage	$V_{SW}$ = -0.6 to 2.0 V $V_{CNTRL}$ =0 to $V_{DD}$	5.0	-500		500	nA
loz	Off-State Leakage for Open Data Paths	$V_{SW}\text{=}~0.0 \leq \text{DATA} \leq 2.0~\text{V}$	5.0	-0.5		0.5	μA
I <sub>CL</sub>	On-State Leakage for Closed Data Paths <sup>(4)</sup>	$V_{SW}\text{=}~0.0 \leq \text{DATA} \leq 2.0~\text{V}$	5.0	-0.5		0.5	μA
I <sub>OFF</sub>	Power-Off Leakage Current (All I/O Ports)	V <sub>SW</sub> = 0 V or 2.0 V	0	-500		500	nA
R <sub>ON</sub>	Switch On Resistance	$V_{SW}$ = 0 V, $I_{ON}$ =-8 mA	1.5		5.4	8.0	Ω
$\Delta R_{ON}$	Difference in R <sub>ON</sub> Between Positive-Negative	V <sub>SW</sub> = 0 V, I <sub>ON</sub> =-8 mA	1.5		0.1		Ω
R <sub>ONF</sub>	Flatness for R <sub>ON</sub>	$\label{eq:V_SW} \begin{array}{l} V_{SW} \!\!\!\!= 0 \leq \! DATA \leq \! 2.0 \ V, \\ I_{ON} \!\!\!\!= \! 8 \ mA \end{array}$	1.5		0.9		Ω
Icc	Quiescent Supply Current	$V_{/OE}$ =0, $V_{SEL}$ =0 or $V_{DD}$ , I_OUT=0	5.0		12	30	μA
I <sub>CCZ</sub>	Quiescent Supply Current (High Impedance)		5.0			1	μA
I <sub>CCT</sub>	Increase in Quiescent Supply Current per V <sub>CNTRL</sub>	$V_{SEL}$ or $V_{/OE}$ =1.5 V	5.0		5	15	μA

Note:

4. For this test, the data switch is closed with the respective switch pin floating.

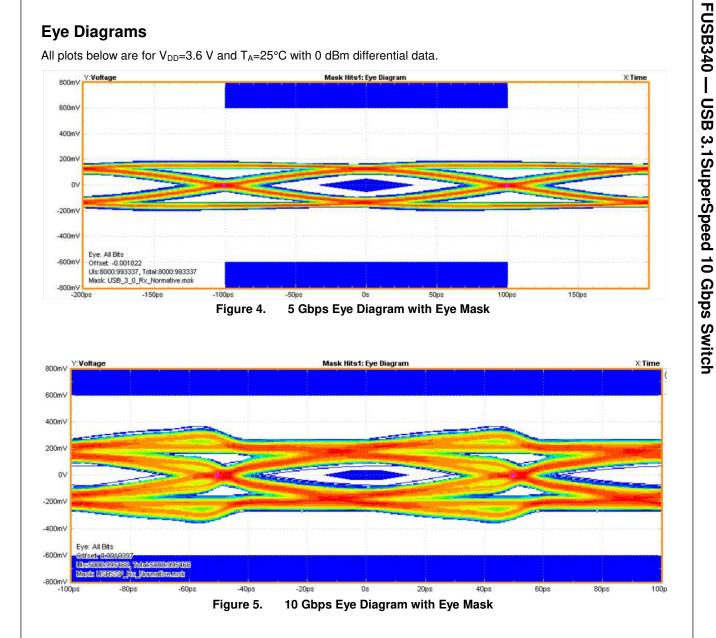
### AC Electrical Characteristics

All typical value are for  $V_{\text{DD}}$  =3.6 V and  $T_{\text{A}}\text{=}25^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Condition	V <sub>DD</sub> (V)	T <sub>A</sub> = -40°C to +85°C			Unit
				Min.	Тур.	Max.	Unit
t <sub>ON</sub>	Turn-On Time, S to Output	$ \begin{array}{l} R_{L} = 50 \ \Omega, \ C_{L} = 0 \ pF, \ V_{SW} = 0 \ V, \\ V_{SW} = 0.6 \ V \end{array} $	1.5 to 5.0 V		350	600	ns
t <sub>OFF</sub>	Turn-Off Time, S to Output	$ \begin{array}{l} R_{L} = 50 \ \Omega, \ C_{L} = 0 \ pF, \ V_{SW} = 0 \ V, \\ V_{SW} = 3.3 \ V \end{array} $	1.5 to 5.0 V		125	300	ns
t <sub>ZHM,ZL</sub>	Enable Time, /OE to Output	$R_L=50 \Omega, C_L=0pF, V_{SW}=0.6 V$	1.5 to 5.0 V		60	150	μs
t <sub>lzm,hz</sub>	Disable Time, /OE to Output	$R_L$ =50 $\Omega$ , $C_L$ =0 pF, $V_{SW}$ =0.6 V	1.5 to 5.0 V		35	240	ns
t <sub>PD</sub>	Propagation Delay <sup>(5)</sup>	$C_L=, C_L=0 \text{ pF}, R_L=50 \Omega,$	1.5 to 5.0 V		0.25		ns
t <sub>BBM</sub>	Break-Before-Make <sup>(5)</sup>		1.5 to 5.0 V	100		350	ns
	Differential Off Isolation <sup>(5)</sup>	$V_S=0dBm$ , $R_L=50 \Omega$ , f=2.5 GHz	3.6 V		-28		dB
DOIRR		$V_S=0dBm$ , $R_L=50 \Omega$ , f=5.0 GHz			-25		UD
	Differential Channel Crosstalk <sup>(5)</sup>	$V_S=0dBm$ , R=50 $\Omega$ , f=2.5 GHz	3.6 V		-44		dB
SDDNEXT		V <sub>S</sub> =0dBm, R=50 Ω, f=5.0 GHz			-40		uв
DIL	Differential Incertion Leas <sup>(5)</sup>	$V_{IN}$ =0dBm, f=2.5 GHz, R <sub>L</sub> =50 $\Omega$ , C <sub>L</sub> =0 pF	3.6 V		-1.0		dB
DIL	(All Data Paths)				-1.8		
BW	Differential -3 dB Bandwidth <sup>(5)</sup>	$V_{IN}$ =1 $V_{pk-pk}$ , $R_L$ =50 $\Omega$ , $C_L$ =0 pF, (Both Data Paths)	3.6 V		10		GHz
$t_{\text{SK}(\text{P})}$	Skew of Opposite Transitions of the Same Output <sup>(5)</sup>	$R_{\text{PU}}{=}50~\Omega$ to $V_{\text{DD}},~C_{\text{L}}{=}0~\text{pF}$	3.6 V		6		ps
CIN	Control Pin Input Capacitance <sup>(5)</sup>	V <sub>DD</sub> =0 V, f=1 MHz			2.7		pF
C <sub>ON</sub>	On Capacitance (5)	V <sub>DD</sub> =3.3 V, f=2.5 GHz			0.5		pF
COFF	Off Capacitance <sup>(5)</sup>	V <sub>DD</sub> =3.3 V, f=2.5 GHz			0.4		pF

Note:

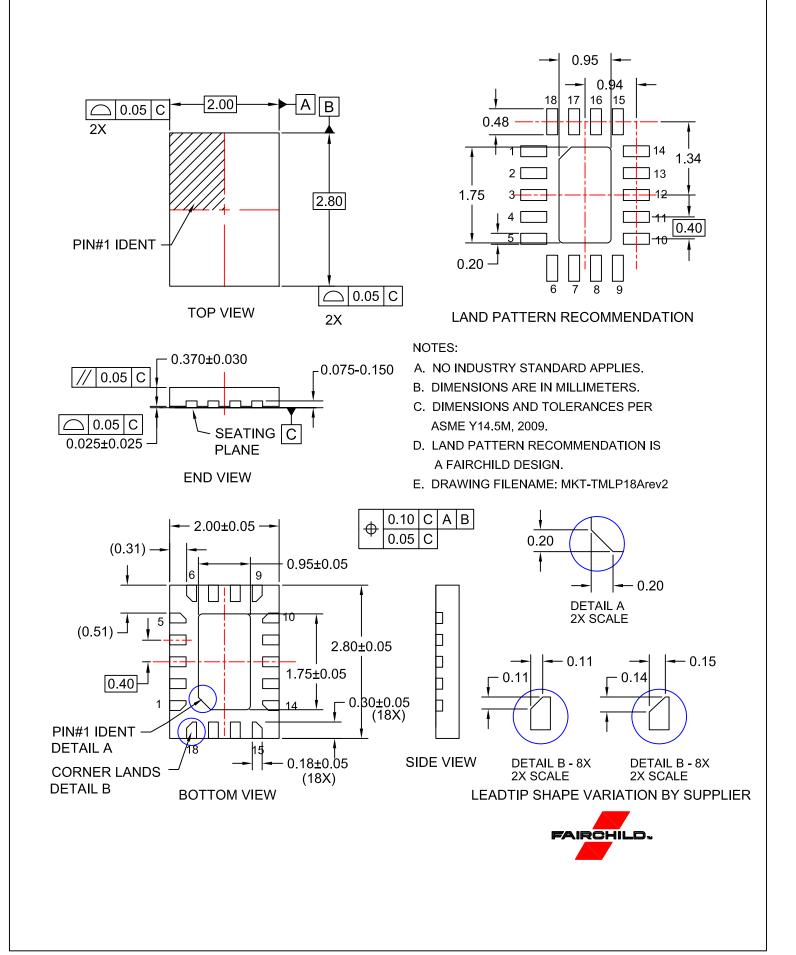
5. Guaranteed by characterization.



The table below pertains to the UMLP Package drawing on the following page.

#### **Product-Specific Dimensions**

Product	А	В		
FUSB340TMX	2.00 mm	2.80 mm		



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